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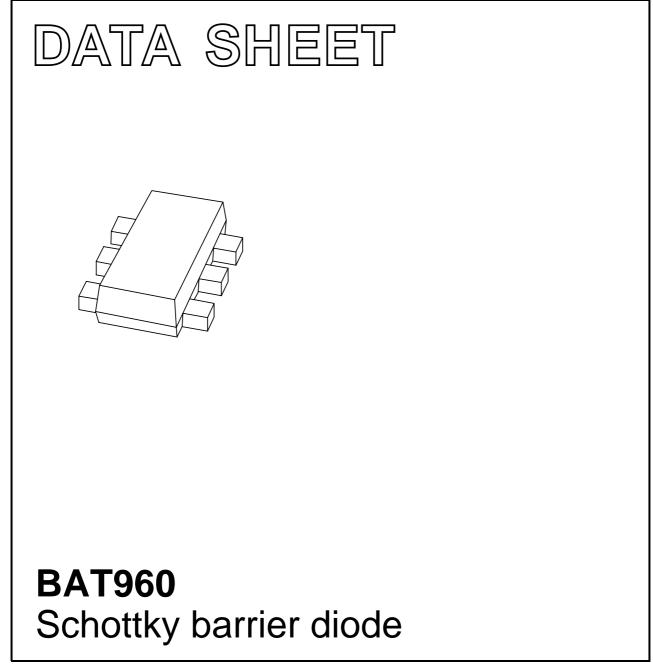
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2002 Jun 24 2003 May 01



Product data sheet

Schottky barrier diode

BAT960

FEATURES

- High current capability
- Very low forward voltage
- Ultra small plastic SMD package
- Flat leads: excellent coplanarity and improved thermal behaviour.

APPLICATIONS

- Ultra high-speed switching
- rectification
- DC/DC conversion
- Switch mode power supply
- Inverse polarity protection.

GENERAL DESCRIPTION

Planar Schottky barrier diode with an integrated guard ring for stress protection in a SOT666 ultra small SMD plastic package.

| INNING | | | |
|--------|-------------|--|--|
| PIN | DESCRIPTION | | |
| 1 | cathode | | |
| 2 | cathode | | |
| 3 | anode | | |
| 4 | anode | | |
| 5 | cathode | | |
| 6 | cathode | | |

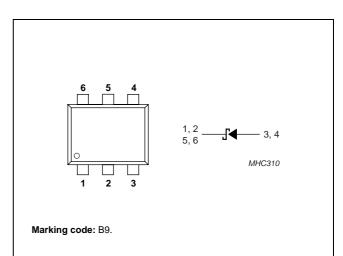


Fig.1 Simplified outline (SOT666) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| V _R | continuous reverse voltage | | - | 23 | V |
| IF | continuous forward current | | - | 1 | А |
| I _{FSM} | non-repetitive peak forward current | t = 8.3 ms half sinewave; JEDEC method; note 1 | - | 8 | A |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 125 | °C |
| T _{amb} | operating ambient temperature | | -65 | +125 | °C |

Note

1. Only valid, if pins 3 and 4 are connected in parallel.

Schottky barrier diode

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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 405 | K/W |
| | | note 2 | 215 | K/W |

Notes

- 1. Refer to SOT666 standard mounting conditions.
- 2. Mounted on printed circuit-board, 1 cm² copper area.

Soldering

The only recommended soldering method is reflow soldering.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | TYP. | MAX. | UNIT |
|----------------|----------------------------|---|------|------|------|
| V _F | continuous forward voltage | I _F = 10 mA | 240 | 270 | mV |
| | | I _F = 100 mA | 300 | 350 | mV |
| | | $I_F = 1000 \text{ mA}; \text{ note } 1; \text{ see Fig.2}$ | 480 | 550 | mV |
| I _R | reverse current | V _R = 5 V; note 2 | 5 | 10 | μA |
| | | V _R = 8 V; note 2 | 7 | 20 | μΑ |
| | | V_R = 15 V; note 2; see Fig.3 | 10 | 50 | μA |
| C _d | diode capacitance | $V_R = 5 V$; f = 1 MHz; see Fig.4 | 19 | 25 | pF |

Notes

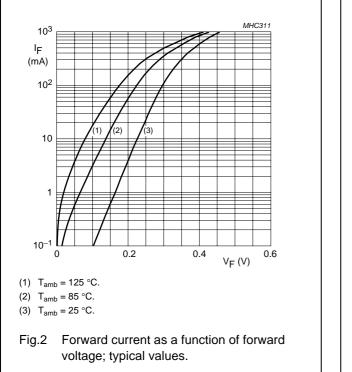
1. Only valid, if pins 1, 2, 5 and 6 are soldered on a 1 cm^2 copper solder land.

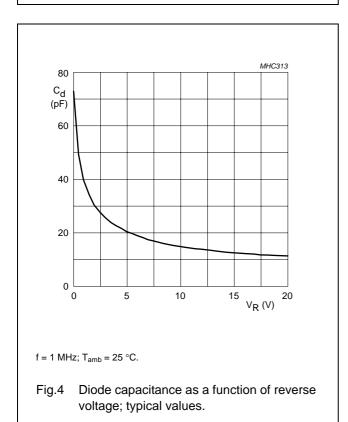
2. Pulse test: $t_p = 300 \ \mu s$; $\delta = 0.02$.

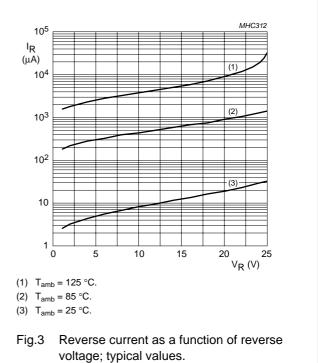
Schottky barrier diode

BAT960







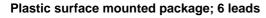


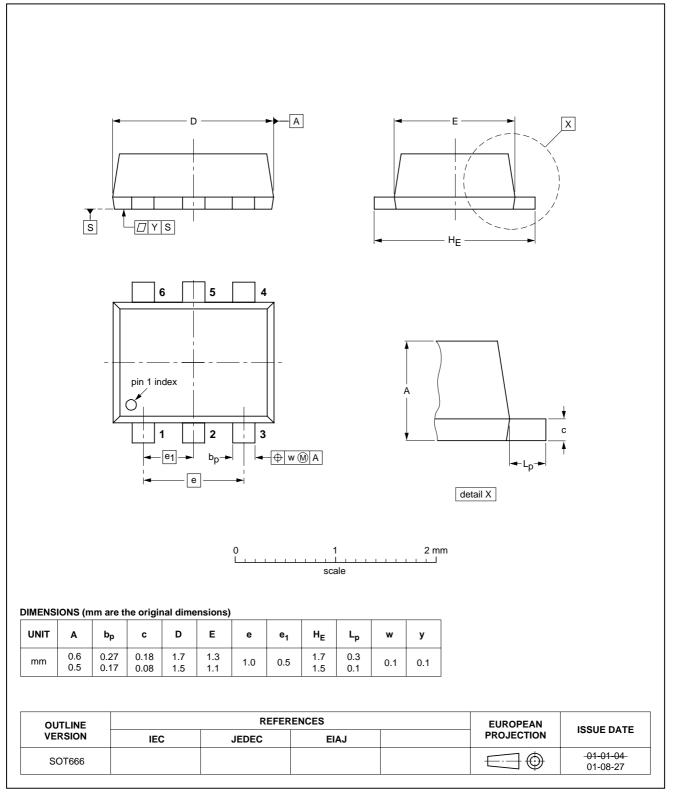
BAT960

SOT666

Schottky barrier diode

PACKAGE OUTLINE





Schottky barrier diode

BAT960

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

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Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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